TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

2SC5612

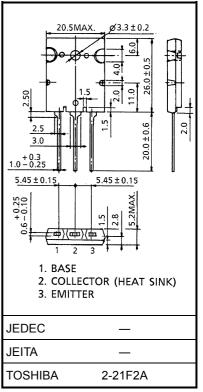
HORIZONTAL DEFLECTION OUTPUT FOR COLOR TV

Unit: mm

- High Voltage : $V_{CBO} = 2000 V$
- Low Saturation Voltage : V_{CE} (sat) = 3 V (Max.)
- High Speed
- : $t_f = 0.15 \mu s$ (Typ.)

MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Base Voltage		V _{CBO}	2000	V	
Collector-Emitter Voltage		V _{CEO}	900	V	
Emitter-Base Voltage		V _{EBO}	5	V	
Collector Current	DC	Ι _C	22	A	
	Pulse	I _{CP}	44		
Base Current		Ι _Β	11	А	
Collector Power Dissipation		P _C	220	W	
Junction Temperature		Тј	150	°C	
Storage Temperature Range		T _{stg}	-55~150	°C	

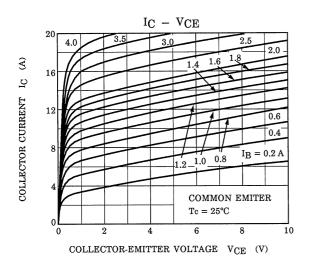


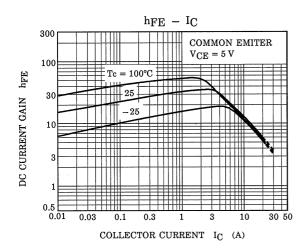
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

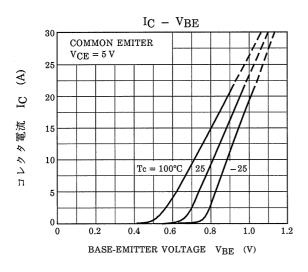
Weight: 9.75 g (typ.)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Collector Cut-off Current		I _{CBO}	$V_{CB} = 2000 V, I_E = 0$	_	_	1	mA
Emitter Cut-off Current		I _{EBO}	V _{EB} = 5 V, I _C = 0	-	-	100	μA
Collector-Emitter Breakdown Voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	900	_	—	V
DC Current Gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 2 A	15	_	50	_
		h _{FE (2)}	V _{CE} = 5 V, I _C = 9 A	9.5	-	18.5	
		h _{FE (3)}	V _{CE} = 5 V, I _C = 17 A	4.8	-	9.0	
Collector-Emitter Saturation Voltage		V _{CE (sat)}	I _C = 17 A, I _B = 4.25 A	-	-	3	V
Base-Emitter Saturation Voltage		V _{BE (sat)}	I _C = 17 A, I _B = 4.25 A	-	_	1.3	V
Transition Frequency		f _T	V _{CE} = 10 V, I _C = 0.1 A	_	2	_	MHz
Collector Output Capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	470	_	pF
Switching Time	Storage Time	t _{stg}	I _{CP} = 8 A, I _{B1} (end) = 1A f _H = 32 kHz	_	4.0	5.0	μs
	Fall Time	t _f		_	0.15	0.35	

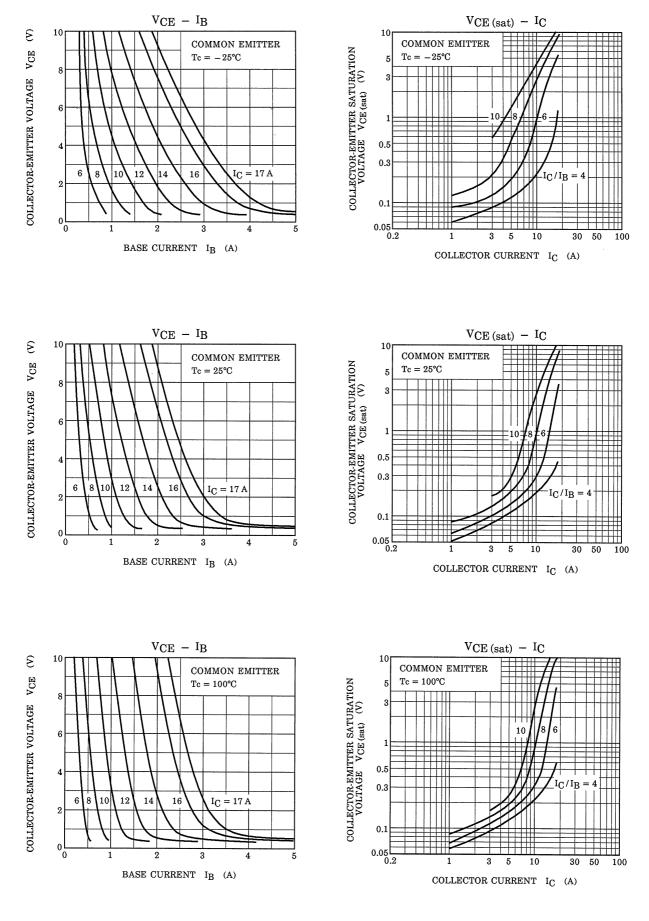
TOSHIBA





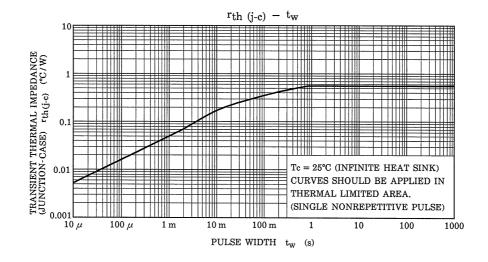


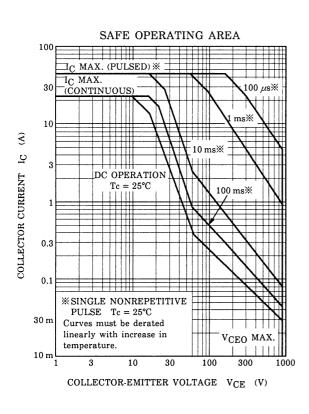
TOSHIBA

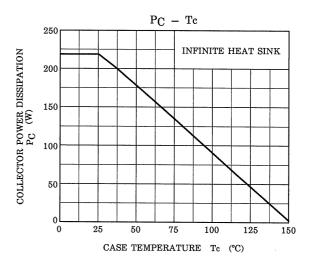


2001-08-20

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